Analog Power AM7338N

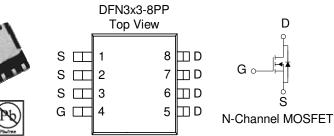
N-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low $r_{DS(on)}$ provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe DFN3x3-8PP saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY				
V _{DS} (V)	$I_{D}(A)$			
20	$6.9 @ V_{GS} = 10V$	19		
30	$9.8 @ V_{GS} = 4.5V$	16		



ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)						
Parameter			Limit	Units		
Drain-Source Voltage			30	V		
Gate-Source Voltage	V_{GS}	±20	V			
Continuous Drain Current ^a	T _A =25°C	T_	±19			
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	ъ	±16	A		
Pulsed Drain Current ^b	I_{DM}	±40				
Continuous Source Current (Diode Conduction) ^a	I_S	2	A			
D D: : .: a	T _A =25°C	D	3.5	W		
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	r _D	2	VV		
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to 150	°C			

HALOGEN FREE

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
Maximum Junction-to-Case ^a	t <= 5 sec	$R_{ heta JC}$	25	°C/W		
Maximum Junction-to-Ambient ^a	t <= 5 sec	$R_{ heta JA}$	50	°C/W		

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

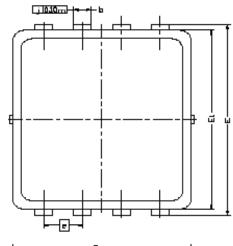
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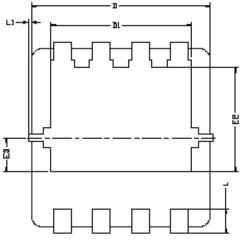
SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)							
Danisanakan	Ch - l	T C 1142	Limits			TT •4	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	VGS(th)	$V_{DS} = V_{GS}$, $I_D = 250 \mathrm{uA}$	1		3	V	
Gate-Body Leakage	Igss	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	$I_{ m DSS}$	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Diam Current	1022	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25		
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			A	
D : G O D : A	***************************************	$V_{GS} = 10 \text{ V}, I_{D} = 10 \text{ A}$			6.9		
Drain-Source On-Resistance ^A	fDS(on)	$V_{GS} = 4.5 \text{ V}, I_D = 8 \text{ A}$			9.8	mΩ	
Forward Tranconductance ^A	gs	$V_{DS} = 15 \text{ V}, I_{D} = 10 \text{ A}$		40		S	
Diode Forward Voltage	V _{SD}	Is = 2.3 A, VGS = 0 V		0.7		V	
Dynamic ^b							
Total Gate Charge	Qg	N 15 N N 45 N		11			
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_{D} = 10 \text{ A}$		6		nC	
Gate-Drain Charge	Q_{gd}	ID = IO A		4]	
Input Capacitance	Ciss	$V_{DS} = 15 \text{ V. } V_{GS} = 0 \text{ V.}$ f		1302			
Output Capacitance	Coss	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1MHz		423		pF	
Reverse Transfer Capacitance	Crss			171			
Turn-On Delay Time	t _{d(on)}			10			
Rise Time	tr	$V_{\rm DD} = 25 \ {\rm V}, \ {\rm RL} = 25 \ {\rm \Omega} \ \ , \ {\rm ID} = 1 \ {\rm A}, \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$		5		nS	
Turn-Off Delay Time	$t_{d(off)}$			22			
Fall-Time	t_{f}			4			

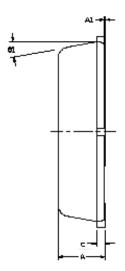
- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information







DIM.	MILLIMETERS			INCHES		
	MIN		MAX	MIN	NOM	MAX
Α	0,700	0'80	0.900	0.0276	0.0315	0.0354
A1	0.00		0.05	0.000	-	0.002
٥	0.24	0.30	0.35	0.009	0.012	0.014
2	0.10	0.152	0.25	0,004	0,006	0.010
ם	3.00 BSC			0.118 BSC		
D1	2.35 BCC			0.093 BSC		
Ε	3,20 BSC			3.20 BSC 0.126 BSC		
E1	3.00 BSC			٥	.118 BS	:C
E5	1.75 BSC			a.	069 BS	C 2
E3	0.575 BSC			0.	023 BS	30
6	0.65 BSC			Ō.	026 BS	C 2
Г	0,30	0,40	0,50	0,0118	0.0157	0.0197
L1			0.100	D		0.004
9 1	٥°	10*	12*	0*	10°	12*